

SOD-323 Plastic-Encapsulate ESD Protection Diodes

DESCRIPTION

The GBLCxxC Series are ultra low capacitance transient voltage suppressor arrays, designed to protect applications such as portable electronics and SMART phones. This series is available in both unidirectional and bidirectional configurations and is rated at 300 Watts for an 8/20 μ s wave shape.

The GBLCxxC and Series meets IEC 61000-4-2 (ESD) and IEC 61000-4-4 (EFT) requirements. At higher operating frequencies or faster edge rates, insertion loss and signal integrity are a major concern. This series offers a ultra low capacitance and low leakage current in a miniature SOD-323 package.

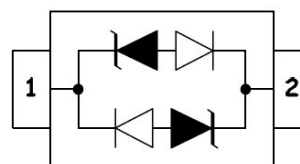
Features

- ◆ Peak Power Dissipation 300W (8/20 μ s)
- ◆ IEC61000-4-2 (ESD) ± 15 kV (air), ± 8 kV (contact)
- ◆ IEC61000-4-4 (EFT) 40A (5/50ns)
- ◆ Protects one I/O line (bidirectional)
- ◆ Low clamping voltage
- ◆ Working voltages : 3V, 5V, 8V, 12V, 15V, 24V
- ◆ Response Time is < 1 ns
- ◆ Meets MSL 1 Requirements

Pin Configuration



Cir



Applications

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

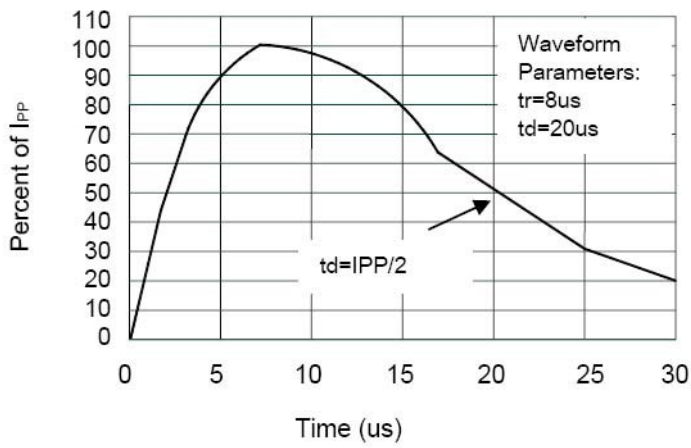
Parameter	Symbol	Value	Unit
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Peak Pulse Power($t_p=8/20\mu\text{s}$ waveform)	P _{PP}	300	W
Operating Temperature	T _{OPT}	-55 to +150	°C
Storage Temperature	T _{STG}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	T _L	260(10 sec.)	°C

The above data are for reference only.

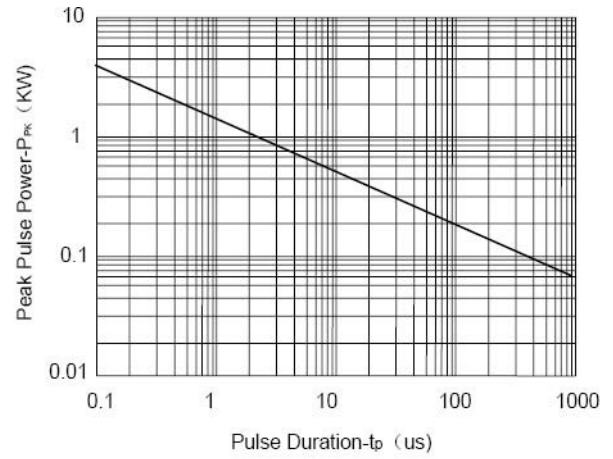
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

PART NUMBER	DEVICE MARKING	V _{RWM} (V) (max.)	V _B (V) (min.)	I _T (mA)	V _{C@1A} (V) (max.)	V _C (V) (max.) (@A)		I _R (μA) (max.)	C _T (pF) (typ.)
GBLC03C	CC	3.3	4.0	1	7.0	13.9	8	2	0.8
GBLC05C	AC	5.0	6.0	1	9.8	18.3	8	1	0.8
GBLC08C	BC	8.0	8.5	1	13.4	18.5	8	1	0.8
GBLC12C	DC	12.0	13.3	1	19.0	28.6	6	1	0.8
GBLC15C	EC	15.0	16.7	1	24.0	31.8	5	1	0.8
GBLC24C	HC	24.0	26.7	1	43.0	56.0	3	1	0.8

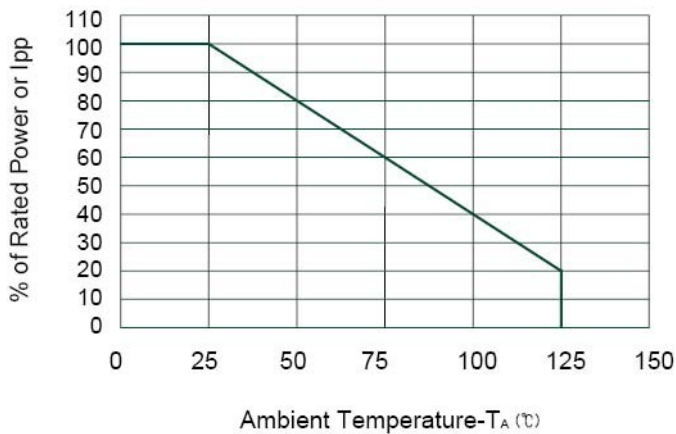
ELECTRICAL CHARACTERISTICS CURVE



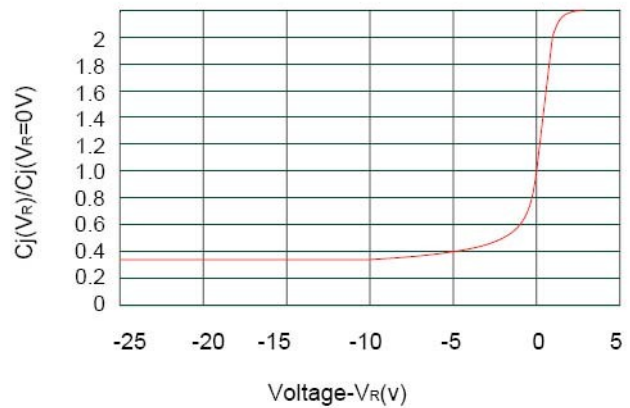
Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve



Junction Capacitance vs. Reverse Voltage